

Description

The GM71C4100B/BL is the new generation dynamic RAM organized 4,194,304 x 1 bit. GM71C4100B/BL has realized higher density, higher performance and various functions by utilizing advanced CMOS process technology. The GM71C4100B/BL offers Fast Page Mode as a high speed access Mode. Multiplexed address inputs permit the GM71C4100B/BL to be packaged in a standard 300mil 20pin plastic SOJ, standard 400mil 20pin plastic ZIP, and standard 300mil 20pin plastic TSOP II. The package size provides high system bit densities and is compatible with widely available automated testing and insertion equipment. System oriented features include single power supply of $5V \pm 10\%$ tolerance, direct interfacing capability with high performance logic families such as Schottky TTL.

Features

- 4,194,304 Words x 1 Bit Organization
- Fast Page Mode Capability
- Single Power Supply ($5V \pm 10\%$)
- Fast Access Time & Cycle Time

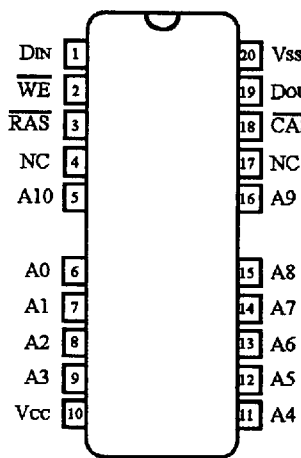
(Unit: ns)

	t _{rac}	t _{cac}	t _{rc}	t _{pc}
GM71C4100B/BL-60	60	15	110	40
GM71C4100B/BL-70	70	20	130	45
GM71C4100B/BL-80	80	20	150	50

- Low Power
Active : 605/550/495mW (MAX)
Standby : 5.5mW (CMOS level : MAX)
1.1mW (L-series)
- $\overline{\text{RAS}}$ Only Refresh, $\overline{\text{CAS}}$ before $\overline{\text{RAS}}$ Refresh, Hidden Refresh Capability
- All inputs and outputs TTL Compatible
- 1024 Refresh Cycles/16ms
- 1024 Refresh Cycles/128ms (L-series)
- Battery Back Up Operation (L-series)

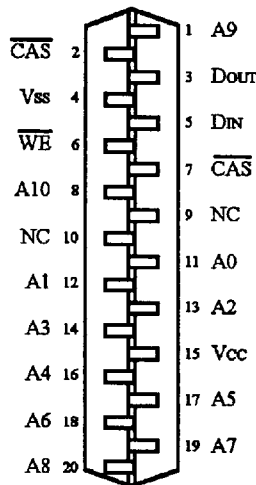
Pin Configuration

20 (26) SOJ



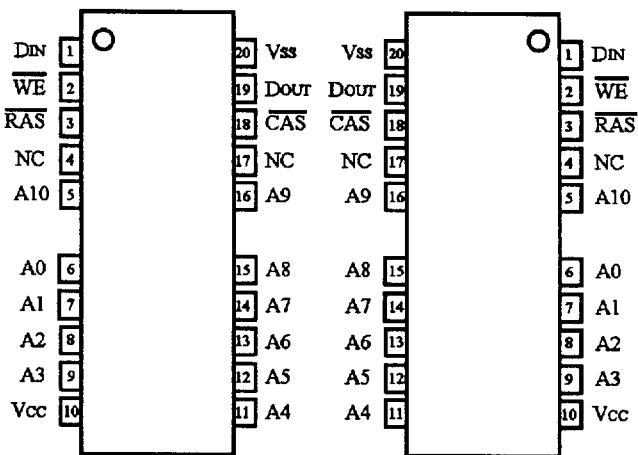
(Top View)

20 ZIP



(Bottom View)

20 (26) TSOP II



GM71C4100BT/BLT

GM71C4100BR/BLR

(Top View)

Pin Description

Pin	Function	Pin	Function
A0-A10	Address Inputs	$\overline{\text{CAS}}$	Column Address Strobe
A0-A9	Refresh Address Inputs	$\overline{\text{WE}}$	Read/Write Enable
D_{IN}	Data Input	V_{CC}	Power (+5V)
D_{OUT}	Data Output	V_{SS}	Ground
$\overline{\text{RAS}}$	Row Address Strobe	NC	No Connection

Ordering Information

Type No.	Access Time	Package
GM71C4100BJ/BLJ-60 GM71C4100BJ/BLJ-70 GM71C4100BJ/BLJ-80	60 ns 70 ns 80 ns	300 Mil, 20 (26) Pin Plastic SOJ
GM71C4100BZ/BLZ-60 GM71C4100BZ/BLZ-70 GM71C4100BZ/BLZ-80	60 ns 70 ns 80 ns	400 Mil, 20 Pin Plastic ZIP
GM71C4100BT/BLT-60 GM71C4100BT/BLT-70 GM71C4100BT/BLT-80	60 ns 70 ns 80 ns	300 Mil, 20 (26) Pin Plastic TSOP II (Normal Type)
GM71C4100BR/BLR-60 GM71C4100BR/BLR-70 GM71C4100BR/BLR-80	60 ns 70 ns 80 ns	300 Mil, 20 (26) Pin Plastic TSOP II (Reverse Type)

Absolute Maximum Ratings*

Symbol	Parameter	Rating	Unit
T_A	Ambient Temperature under Bias	0 ~ 70	°C
T_{STG}	Storage Temperature (Plastic)	-55 ~ 125	°C
$\text{V}_{\text{IN}}/\text{V}_{\text{OUT}}$	Voltage on any Pin Relative to V_{SS}	-1.0 ~ 7.0	V
V_{CC}	Voltage on V_{CC} Relative to V_{SS}	-1.0 ~ 7.0	V
I_{OUT}	Short Circuit Output Current	50	mA
P_D	Power Dissipation	1.0	W

*Note: Operation at or above Absolute Maximum Ratings can adversely affect device reliability.

Recommended DC Operating Conditions ($T_A = 0 \sim 70^\circ\text{C}$)

Symbol	Parameter	Min	Typ	Max	Unit
V_{CC}	Supply Voltage	4.5	5.0	5.5	V
V_{IH}	Input High Voltage	2.4	-	6.5	V
V_{IL}	Input Low Voltage	-1.0	-	0.8	V

DC Electrical Characteristics ($V_{CC} = 5V \pm 10\%$, $T_A = 0 \sim 70^\circ C$)

Symbol	Parameter	Min	Max	Unit	Note
V_{OH}	Output Level Output "H" Level Voltage ($I_{OUT} = -5mA$)	2.4	V_{CC}	V	
V_{OL}	Output Level Output "L" Level Voltage ($I_{OUT} = 4.2mA$)	0	0.4	V	
I_{CC1}	Operating Current Average Power Supply Operating Current ($\overline{RAS}$, $\overline{CAS}$ Cycling: $t_{RC} = t_{RC \min}$)	60ns	-	110	mA 1, 2
		70ns	-	100	
		80ns	-	90	
I_{CC2}	Standby Current (TTL) Power Supply Standby Current ($\overline{RAS}$, $\overline{CAS} = V_{IH}$, $DOUT = High-Z$)	-	2	mA	
I_{CC3}	$\overline{RAS}$ -Only Refresh Current Average Power Supply Current $\overline{RAS}$ -Only Refresh Mode ($\overline{RAS}$ Cycling, $\overline{CAS} = V_{IH}$, $t_{RC} = t_{RC \min}$)	60ns	-	110	mA 2
		70ns	-	100	
		80ns	-	90	
I_{CC4}	Fast Page Mode Current Average Power Supply Current Fast Page Mode ($\overline{RAS} = V_{IL}$, $\overline{CAS}$, Address Cycling: $t_{RC} = t_{RC \min}$)	60ns	-	110	mA 1, 3
		70ns	-	100	
		80ns	-	90	
I_{CC5}	Standby Current (CMOS) Power Supply Standby Current ($\overline{RAS}$, $\overline{CAS} = V_{IH}$, $\overline{WE}$, Address, $DIN = V_{IH}$ or V_{IL} , $DOUT = High-Z$)	-	1	mA	5
		-	200	μA	4, 5
I_{CC6}	$\overline{CAS}$ -before- $\overline{RAS}$ Refresh Current ($t_{RC} = t_{RC \min}$)	60ns	-	110	mA
		70ns	-	100	
		80ns	-	90	
I_{CC7}	Battery Back Up Current (Standby with CBR Refresh) ($t_{RC} = 125\mu s$, $t_{RAS} \leq 1\mu s$, $\overline{WE} = V_{IH}$, $\overline{CAS} = V_{IL}$, Address and $DIN = V_{IH}$ or V_{IL} , $DOUT = High-Z$)	-	300	μA	4, 5
I_{CC8}	Standby Current $\overline{RAS} = V_{IH}$ $\overline{CAS} = V_{IL}$ $DOUT = Enable$	-	5	mA	1
I_{IL}	Input Leakage Current Any Input ($0V \leq V_{IN} \leq 7V$)	-10	10	μA	
I_{OL}	Output Leakage Current ($DOUT$ is Disabled, $0V \leq V_{OUT} \leq 7V$)	-10	10	μA	

Note: 1. I_{CC} depends on output load condition when the device is selected. $I_{CC}(\max)$ is specified at the output open condition.

2. Address can be changed once or less while $\overline{RAS} = V_{IL}$.

3. Address can be changed once or less while $\overline{CAS} = V_{IH}$.

4. L Series.

5. $V_{CC} - 0.2V \leq V_{IH} \leq 6.5V$, $0V \leq V_{IL} \leq 0.2V$.

Capacitance ($V_{CC} = 5V \pm 10\%$, $T_A = 25^\circ C$)

Symbol	Parameter	Min	Max	Unit	Note
C_{I1}	Input Capacitance (Address, D_{IN})	-	5	pF	1
C_{I2}	Input Capacitance (Clocks)	-	7	pF	1
C_O	Output Capacitance (D_{OUT})	-	7	pF	1, 2

Note: 1. Capacitance measured with Boonton Meter or effective capacitance measuring method.
 2. $\overline{CAS} = V_{IH}$ to disable D_{OUT} .

AC Characteristics ($V_{CC} = 5V \pm 10\%$, $T_A = 0 \sim 70^\circ C$, Notes 1, 2, 15)

Test Conditions

Input rise and fall times: 5ns

Output load : 2 TTL gate + C_L (100pF)

Input, output timing reference levels: 0.8V, 2.4V

(Including scope and jig)

Read, Write, Read-Modify-Write and Refresh Cycles (Common Parameters)

Symbol	Parameter	GM71C4100 B/BL-60		GM71C4100 B/BL-70		GM71C4100 B/BL-80		Unit	Note
		Min	Max	Min	Max	Min	Max		
t_{RC}	Random Read or Write Cycle Time	110	-	130	-	150	-	ns	
t_{RP}	$\overline{RAS}$ Precharge Time	40	-	50	-	60	-	ns	
t_{RAS}	$\overline{RAS}$ Pulse Width	60	10,000	70	10,000	80	10,000	ns	
t_{CAS}	$\overline{CAS}$ Pulse Width	15	10,000	20	10,000	20	10,000	ns	
t_{ASR}	Row Address Set-up Time	0	-	0	-	0	-	ns	
t_{RAH}	Row Address Hold Time	10	-	10	-	10	-	ns	
t_{ASC}	Column Address Set-up Time	0	-	0	-	0	-	ns	
t_{CAH}	Column Address Hold Time	15	-	15	-	15	-	ns	
t_{RCD}	$\overline{RAS}$ to $\overline{CAS}$ Delay Time	20	45	20	50	20	60	ns	8
t_{RAD}	$\overline{RAS}$ to Column Address Delay Time	15	30	15	35	15	40	ns	9
t_{RSH}	$\overline{RAS}$ Hold Time	15	-	20	-	20	-	ns	
t_{CSH}	$\overline{CAS}$ Hold Time	60	-	70	-	80	-	ns	
t_{CRP}	$\overline{CAS}$ to $\overline{RAS}$ Precharge Time	10	-	10	-	10	-	ns	
t_T	Transition Time (Rise and Fall)	3	50	3	50	3	50	ns	7
t_{REF}	Refresh Period (1024 Cycles)	-	16	-	16	-	16	ms	
	Refresh Period (1024 Cycles)	-	128	-	128	-	128	ms	L-Series

Read Cycle

Symbol	Parameter	GM71C4100 B/BL-60		GM71C4100 B/BL-70		GM71C4100 B/BL-80		Unit	Note
		Min	Max	Min	Max	Min	Max		
t _{RAC}	Access Time from $\overline{\text{RAS}}$	-	60	-	70	-	80	ns	2,3,16
t _{CAC}	Access Time from $\overline{\text{CAS}}$	-	15	-	20	-	20	ns	3, 4, 14, 16
t _{AA}	Access Time from Address	-	30	-	35	-	40	ns	3, 5, 14, 16
t _{RCS}	Read Command Setup Time	0	-	0	-	0	-	ns	
t _{RCH}	Read Command Hold Time to $\overline{\text{CAS}}$	0	-	0	-	0	-	ns	
t _{RRH}	Read Command Hold Time to $\overline{\text{RAS}}$	0	-	0	-	0	-	ns	
t _{RAL}	Column Address to $\overline{\text{RAS}}$ Lead Time	30	-	35	-	40	-	ns	
t _{OFF}	Output Buffer Turn-off Time	0	15	0	20	0	20	ns	6

Write Cycle

Symbol	Parameter	GM71C4100 B/BL-60		GM71C4100 B/BL-70		GM71C4100 B/BL-80		Unit	Note
		Min	Max	Min	Max	Min	Max		
t _{WCS}	Write Command Setup Time	0	-	0	-	0	-	ns	10
t _{WCH}	Write Command Hold Time	15	-	15	-	15	-	ns	
t _{WP}	Write Command Pulse Width	10	-	10	-	10	-	ns	
t _{RWL}	Write Command to $\overline{\text{RAS}}$ Lead Time	15	-	20	-	20	-	ns	
t _{CWL}	Write Command to $\overline{\text{CAS}}$ Lead Time	15	-	20	-	20	-	ns	
t _{DS}	Data-in Setup Time	0	-	0	-	0	-	ns	11
t _{DH}	Data-in Hold Time	15	-	15	-	15	-	ns	11

Read-Modify-Write Cycle

Symbol	Parameter	GM71C4100 B/BL-60		GM71C4100 B/BL-70		GM71C4100 B/BL-80		Unit	Note
		Min	Max	Min	Max	Min	Max		
t _{RWC}	Read-Modify-Write Cycle Time	130	-	155	-	175	-	ns	
t _{RWD}	$\overline{\text{RAS}}$ to $\overline{\text{WE}}$ Delay Time	60	-	70	-	80	-	ns	10
t _{CWD}	$\overline{\text{CAS}}$ to $\overline{\text{WE}}$ Delay Time	15	-	20	-	20	-	ns	10
t _{AWD}	Column Address to $\overline{\text{WE}}$ Delay Time	30	-	35	-	40	-	ns	10

Refresh Cycle

Symbol	Parameter	GM71C4100 B/BL-60		GM71C4100 B/BL-70		GM71C4100 B/BL-80		Unit	Note
		Min	Max	Min	Max	Min	Max		
t _{CSR}	$\overline{\text{CAS}}$ Set-up Time ($\overline{\text{CAS}}$ -before- $\overline{\text{RAS}}$ Refresh Cycle)	10	-	10	-	10	-	ns	
t _{CHR}	$\overline{\text{CAS}}$ Hold Time ($\overline{\text{CAS}}$ -before- $\overline{\text{RAS}}$ Refresh Cycle)	10	-	10	-	10	-	ns	
t _{RPC}	$\overline{\text{RAS}}$ Precharge to $\overline{\text{CAS}}$ Hold Time	10	-	10	-	10	-	ns	
t _{CPN}	$\overline{\text{CAS}}$ Precharge Time in Normal Mode	10	-	10	-	10	-	ns	

Fast Page Mode Cycle

Symbol	Parameter	GM71C4100 B/BL-60		GM71C4100 B/BL-70		GM71C4100 B/BL-80		Unit	Note
		Min	Max	Min	Max	Min	Max		
t _{PC}	Fast Page Mode Cycle Time	40	-	45	-	50	-	ns	
t _{CP}	Fast Page Mode $\overline{\text{CAS}}$ Precharge Time	10	-	10	-	10	-	ns	
t _{RASC}	Fast Page Mode $\overline{\text{RAS}}$ Pulse Width	-	100,000	-	100,000	-	100,000	ns	14
t _{ACP}	Access Time from $\overline{\text{CAS}}$ Precharge	-	35	-	40	-	45	ns	3,14,16
t _{RHCP}	$\overline{\text{RAS}}$ Hold Time from $\overline{\text{CAS}}$ Precharge	35	-	40	-	45	-	ns	

Fast Page Mode Read-Modify-Write Cycle

Symbol	Parameter	GM71C4100 B/BL-60		GM71C4100 B/BL-70		GM71C4100 B/BL-80		Unit	Note
		Min	Max	Min	Max	Min	Max		
t _{PCM}	Fast Page Mode Read-Modify-Write Cycle Time	60	-	70	-	75	-	ns	
t _{CPW}	$\overline{\text{CAS}}$ Precharge to $\overline{\text{WE}}$ Delay Time	35	-	40	-	45	-	ns	

Test Mode Cycle

Symbol	Parameter	GM71C4100 B/BL-60		GM71C4100 B/BL-70		GM71C4100 B/BL-80		Unit	Note
		Min	Max	Min	Max	Min	Max		
t _{WS}	Test Mode $\overline{\text{WE}}$ Setup Time	0	-	0	-	0	-	ns	
t _{WH}	Test Mode $\overline{\text{WE}}$ Hold Time	10	-	10	-	10	-	ns	



Counter Test Cycle

Symbol	Parameter	GM71C4100 B/BL-60		GM71C4100 B/BL-70		GM71C4100 B/BL-80		Unit	Note
		Min	Max	Min	Max	Min	Max		
t _{CPT}	$\overline{\text{CAS}}$ Precharge Time in Counter Test Cycle	40	-	40	-	40	-	ns	

Notes:

1. AC Measurements assume $t_r = 5\text{ ns}$.
2. Assumes that $t_{\text{rCD}} \leq t_{\text{rCD}}(\text{max})$ and $t_{\text{rAD}} \leq t_{\text{rAD}}(\text{max})$. If t_{rCD} or t_{rAD} is greater than the maximum recommended value shown in this table, t_{rAC} exceeds the value shown.
3. Measured with a load circuit equivalent to 2TTL loads and 100pF.
4. Assumes that $t_{\text{rCD}} \geq t_{\text{rCD}}(\text{max})$ and $t_{\text{rAD}} \leq t_{\text{rAD}}(\text{max})$.
5. Assumes that $t_{\text{rCD}} \leq t_{\text{rCD}}(\text{max})$ and $t_{\text{rAD}} \geq t_{\text{rAD}}(\text{max})$.
6. $t_{\text{off}}(\text{max})$ defines the time at which the output achieves the open circuit condition and is not referenced to output voltage levels.
7. $V_{\text{IH}}(\text{max})$ and $V_{\text{IL}}(\text{max})$ are reference levels for measuring timing of input signals. Also, transition times are measured between V_{IH} and V_{IL} .
8. Operation with the $t_{\text{rAD}}(\text{max})$ limit insures that $t_{\text{rAC}}(\text{max})$ can be met, $t_{\text{rCD}}(\text{max})$ is specified as a reference point only; if t_{rCD} is greater than the specified $t_{\text{rCD}}(\text{max})$ limit, then access time is controlled exclusively by t_{CAC} .
9. Operation with the $t_{\text{rAD}}(\text{max})$ limit insures that $t_{\text{rAC}}(\text{max})$ can be met, $t_{\text{rAD}}(\text{max})$ is specified as a reference point only; if t_{rAD} is greater than the specified $t_{\text{rAD}}(\text{max})$ limit, then access time is controlled exclusively by t_{AA} .
10. t_{WCS} , t_{rWD} , t_{CWD} , t_{AWD} and t_{CPW} are not restrictive operating parameters. They are included in the data sheet as electrical characteristics only if $t_{\text{WCS}} \geq t_{\text{WCS}}(\text{min})$ the cycle is an early write cycle and the data out pin will remain open circuit (high impedance) throughout the entire cycle; if $t_{\text{rWD}} \geq t_{\text{rWD}}(\text{min})$, $t_{\text{CWD}} \geq t_{\text{CWD}}(\text{min})$, $t_{\text{AWD}} \geq t_{\text{AWD}}(\text{min})$ and $t_{\text{CPW}} \geq t_{\text{CPW}}(\text{min})$, the cycle is a read modify write and the data output will contain data read from the selected cell; if neither of the above sets of conditions is satisfied, the condition of the data out (at access time) is indeterminate.
11. These parameters are referenced to $\overline{\text{CAS}}$ leading edge in early write cycles and to $\overline{\text{WE}}$ leading edge in delayed write or a read modify write cycle.
12. An initial pause of 100 μs is required after power up followed by a minimum of eight initialization cycles ($\overline{\text{RAS}}$ only refresh cycle or $\overline{\text{CAS}}$ before $\overline{\text{RAS}}$ refresh cycle). If the internal refresh counter is used, a minimum of eight $\overline{\text{CAS}}$ before $\overline{\text{RAS}}$ refresh cycles is required.
13. t_{RASC} defines $\overline{\text{RAS}}$ pulse width in fast page mode cycles.
14. Access time is determined by the longer of t_{AA} or t_{CAC} or t_{ACP} .



15. Test mode operation specified in this data sheet is 8 bit test function controlled by control address bits RA10, CA10 and CA0. This test mode operation can be performed by $\overline{WE}$ and $\overline{CAS}$ before $\overline{RAS}$ (WCBR) refresh cycle. Refresh during test mode operation will be performed by normal read cycles or by WCBR refresh cycles. When the state of eight test bits accord each other, the condition of the output data is high level. When the state of test bits do not accord, the condition of the output data is low level. Data output pin is DOUT and data input pin is DIN. In order to end this test mode operation, perform a $\overline{RAS}$ only refresh cycle or a $\overline{CAS}$ before $\overline{RAS}$ refresh cycle.
16. In a test mode read cycle, the value of t_{RAC} , t_{AA} , t_{CAC} and t_{ACP} is delayed for 2ns to 5ns for the specified value. These parameters should be specified in test mode cycles by adding the above value to the specified value in this data sheet.

Timing Waveforms

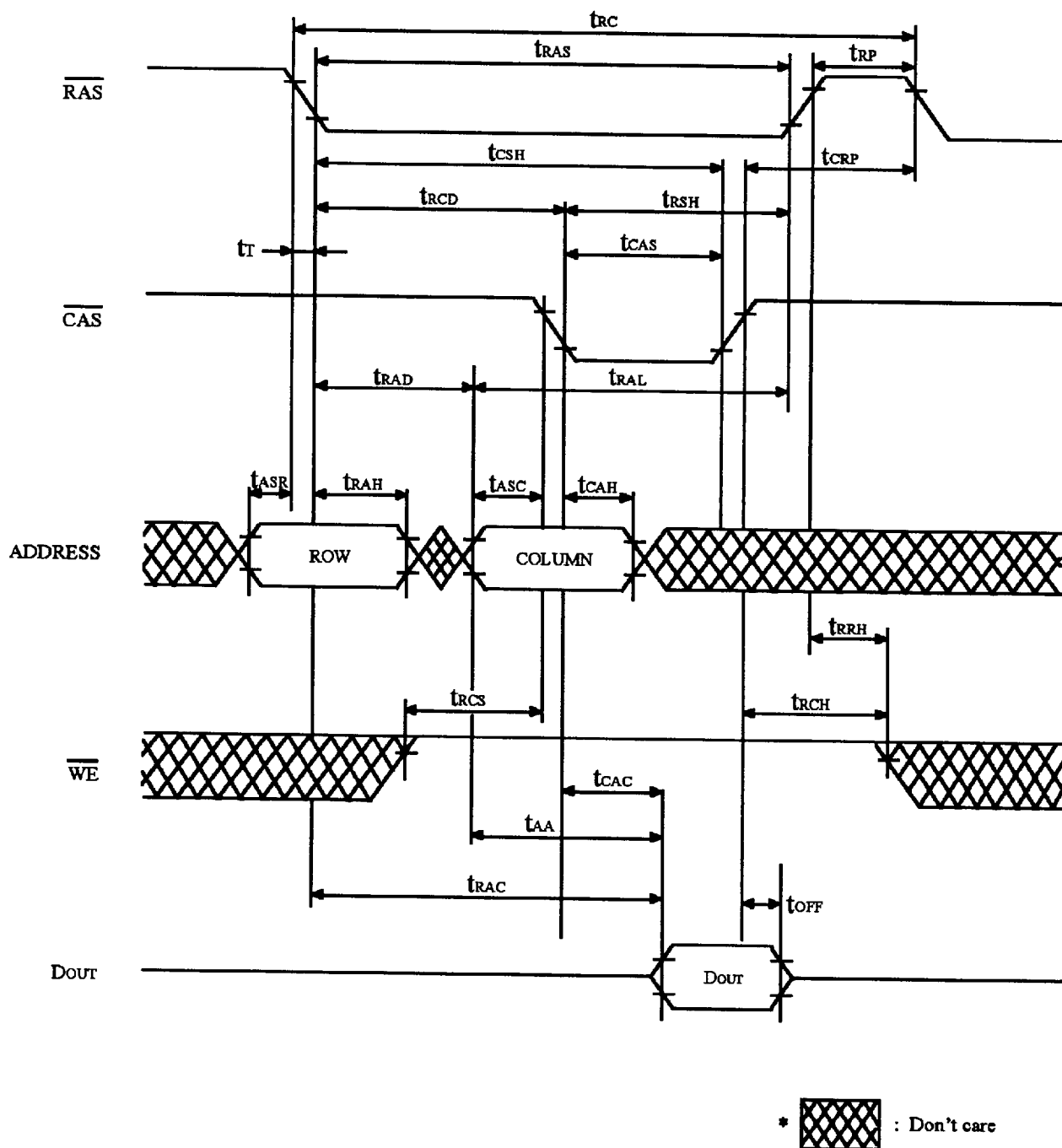
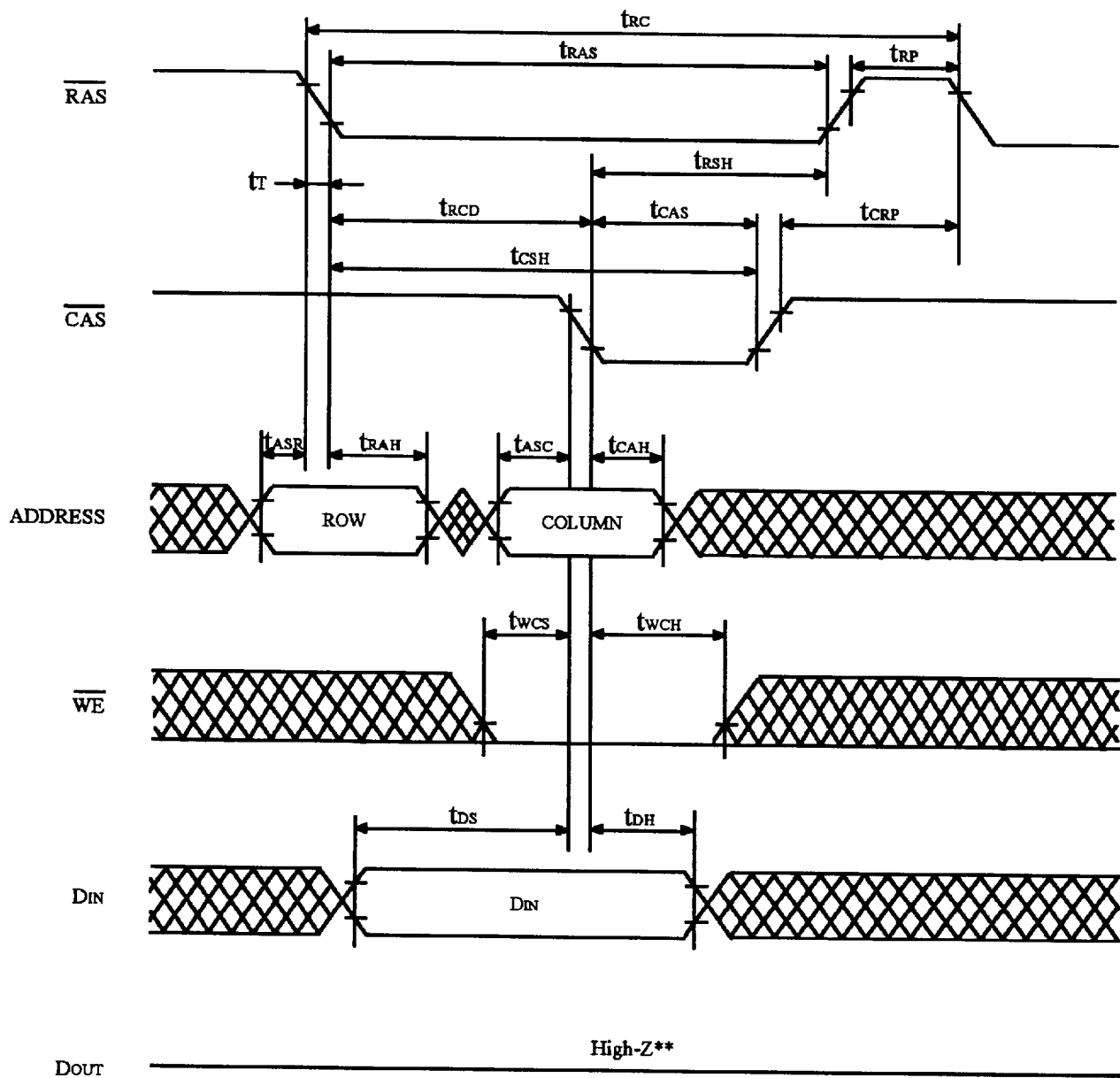


FIGURE 1. READ CYCLE



*  : Don't care

** $t_{WCS} \geq t_{WCS}(\text{min})$

FIGURE 2. EARLY WRITE CYCLE

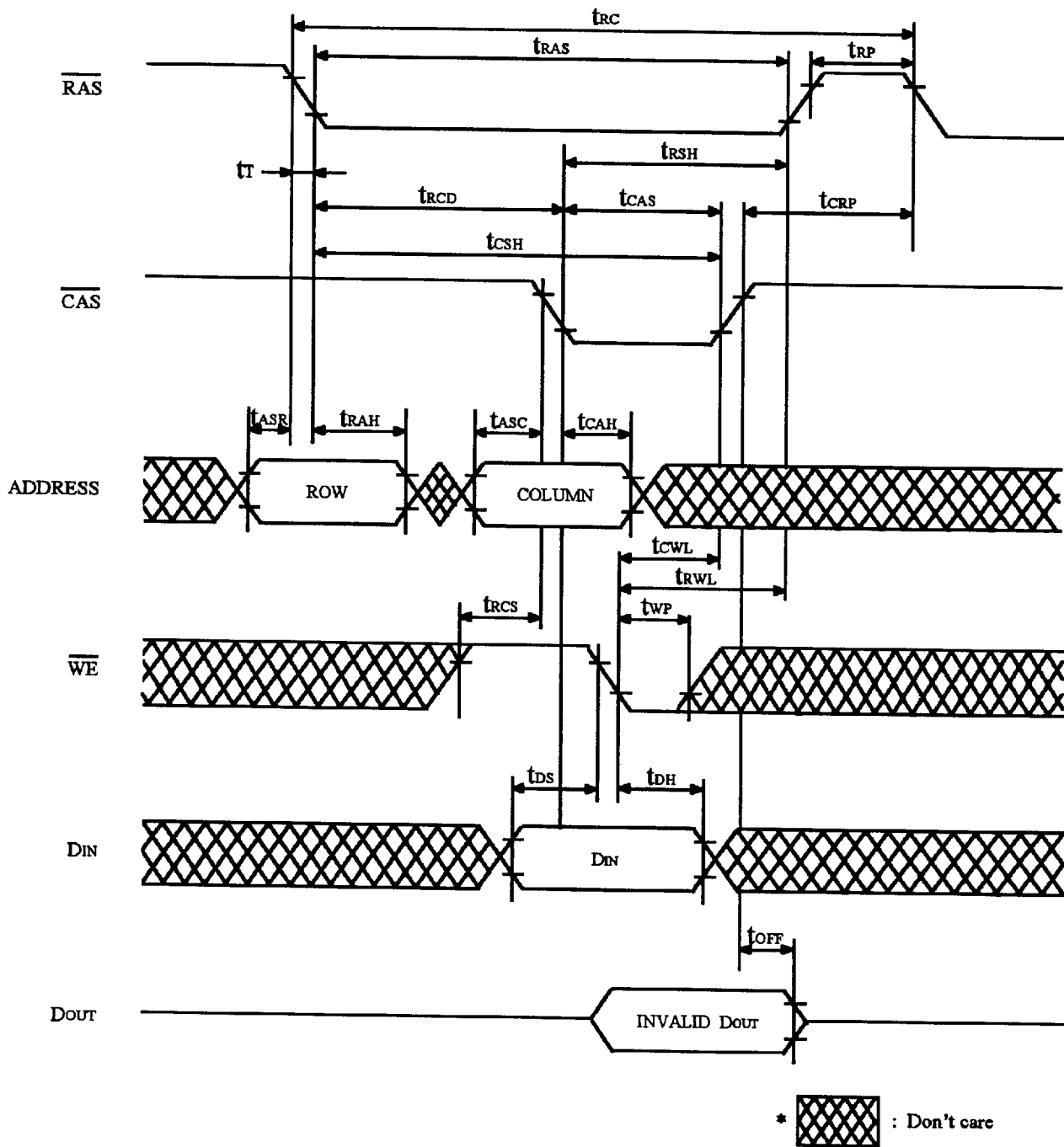


FIGURE 3. DELAYED WRITE CYCLE

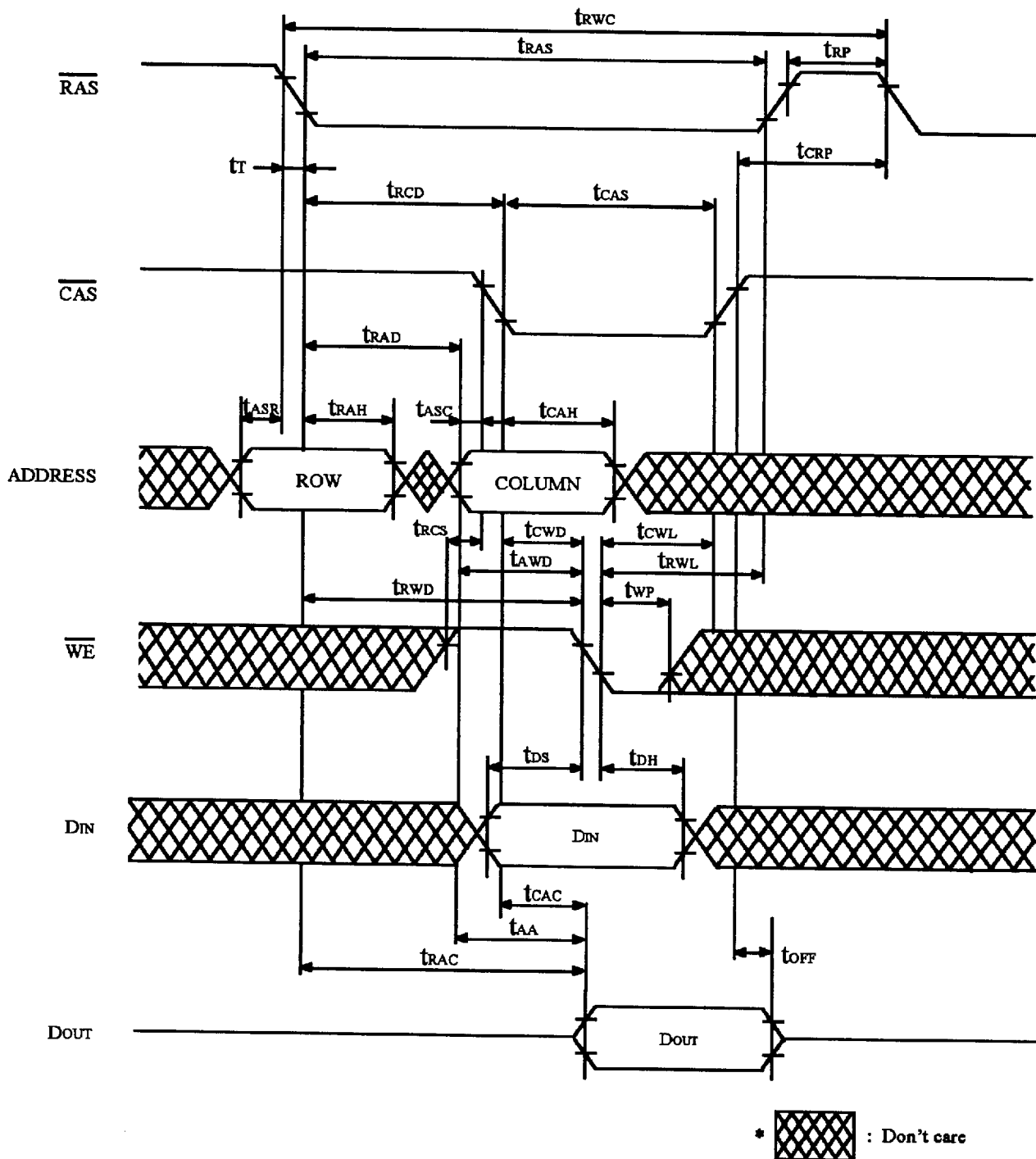
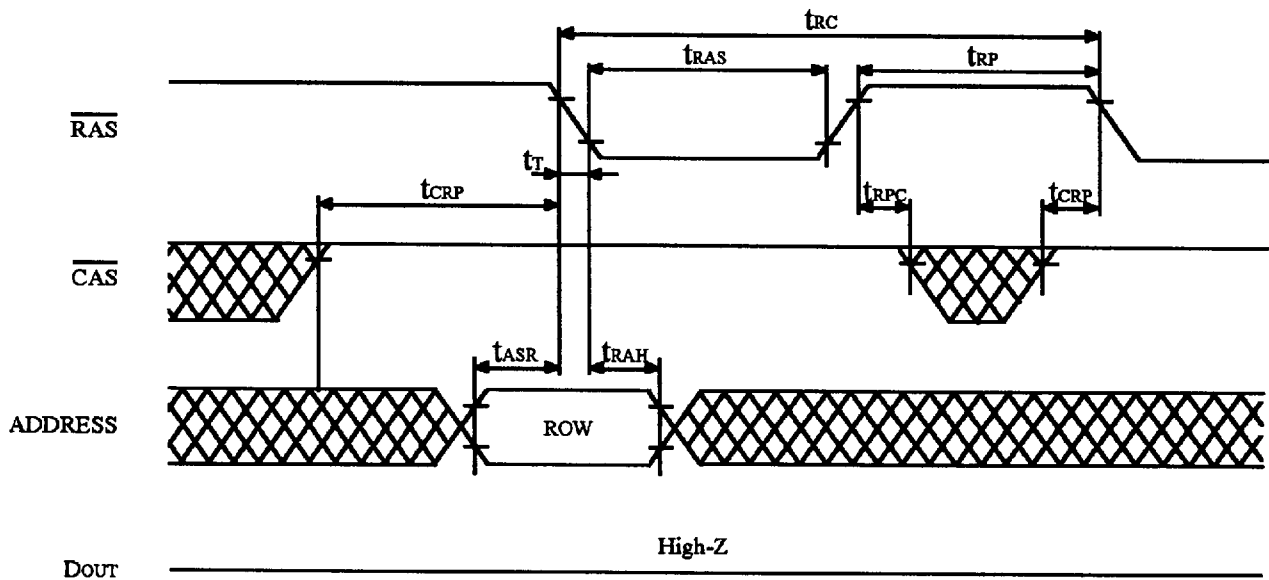


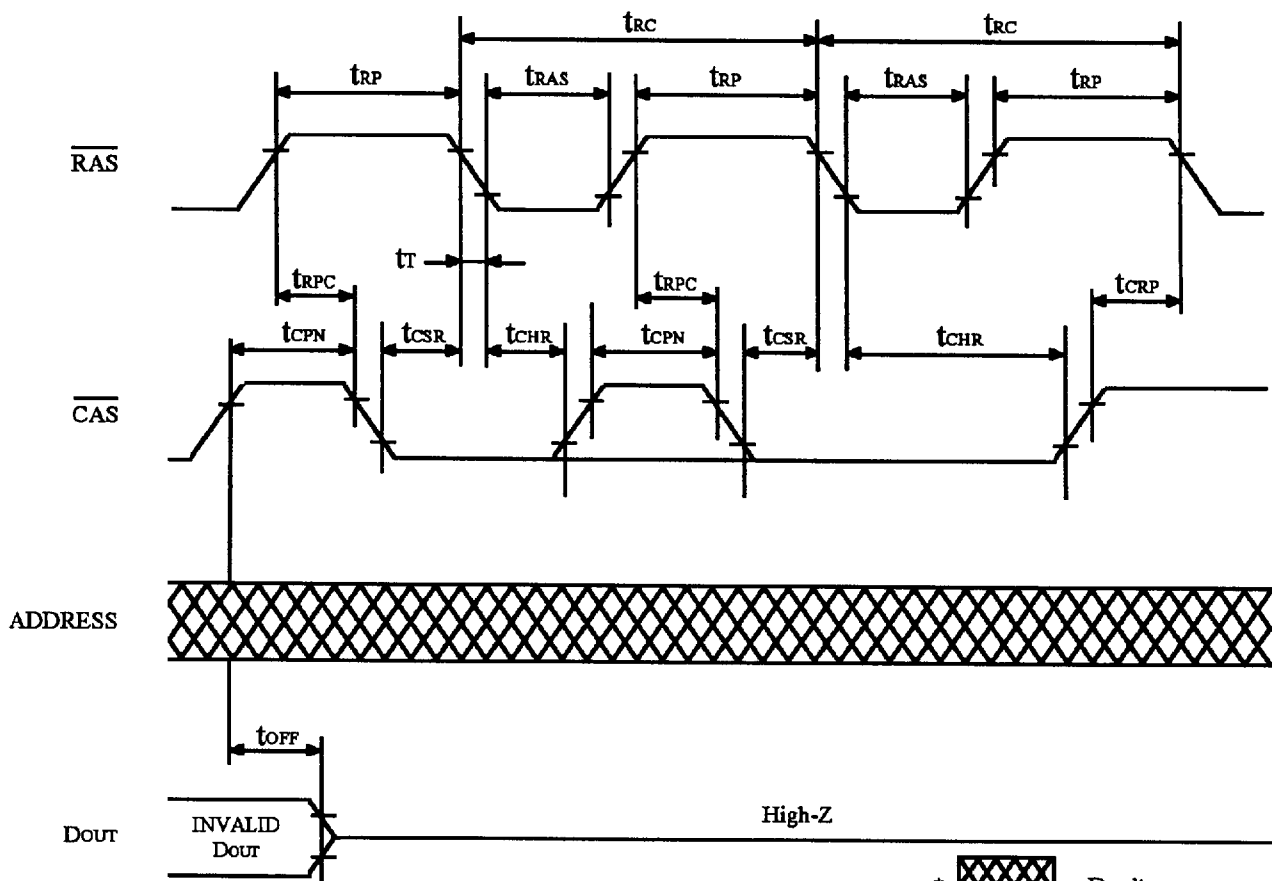
FIGURE 4. READ MODIFY WRITE CYCLE



* $\overline{WE}$: Don't care

FIGURE 5. $\overline{RAS}$ ONLY REFRESH CYCLE

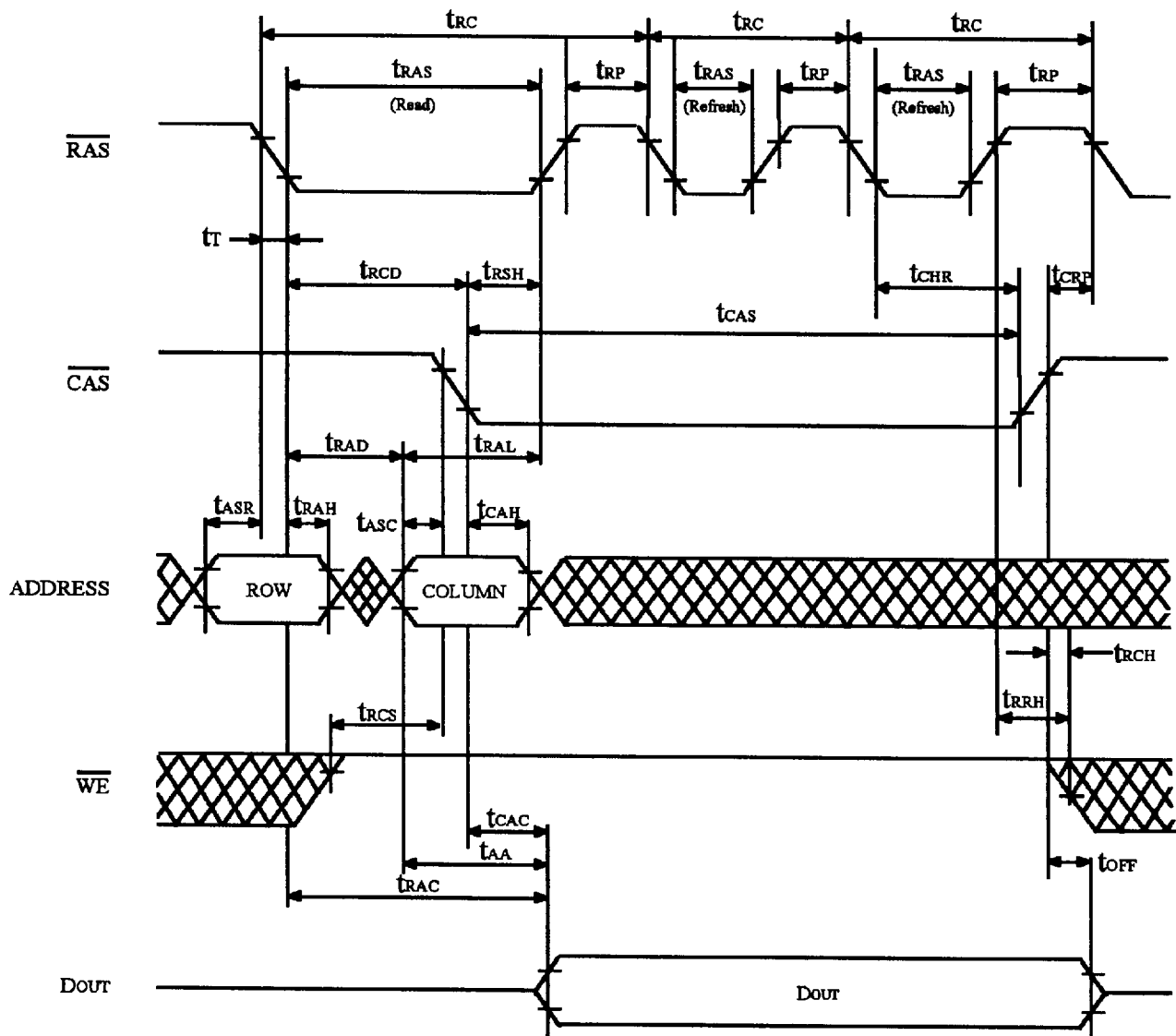
** Refresh address : A0~A9



*  : Don't care

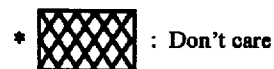
** $\overline{WE}$: V_{IH}

FIGURE 6. $\overline{CAS}$ BEFORE $\overline{RAS}$ REFRESH CYCLE

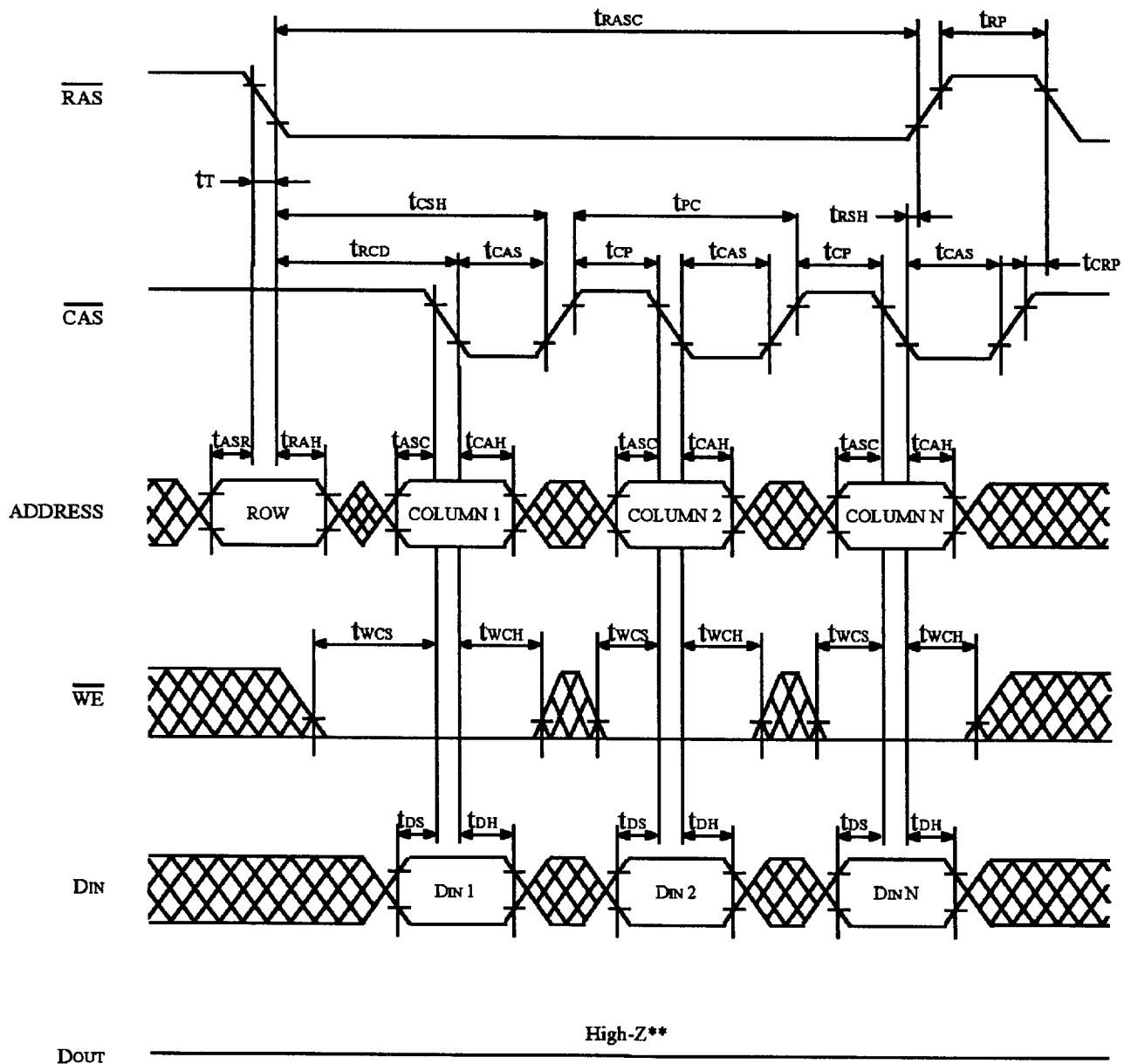


*  : Don't care

FIGURE 7. HIDDEN REFRESH CYCLE



4028757 0005176 381



*  : Don't care

** $t_{WCS} \geq t_{WCS}(\text{min})$

FIGURE 9. FAST PAGE MODE EARLY WRITE CYCLE



FIGURE 10. FAST PAGE MODE DELAYED WRITE CYCLE

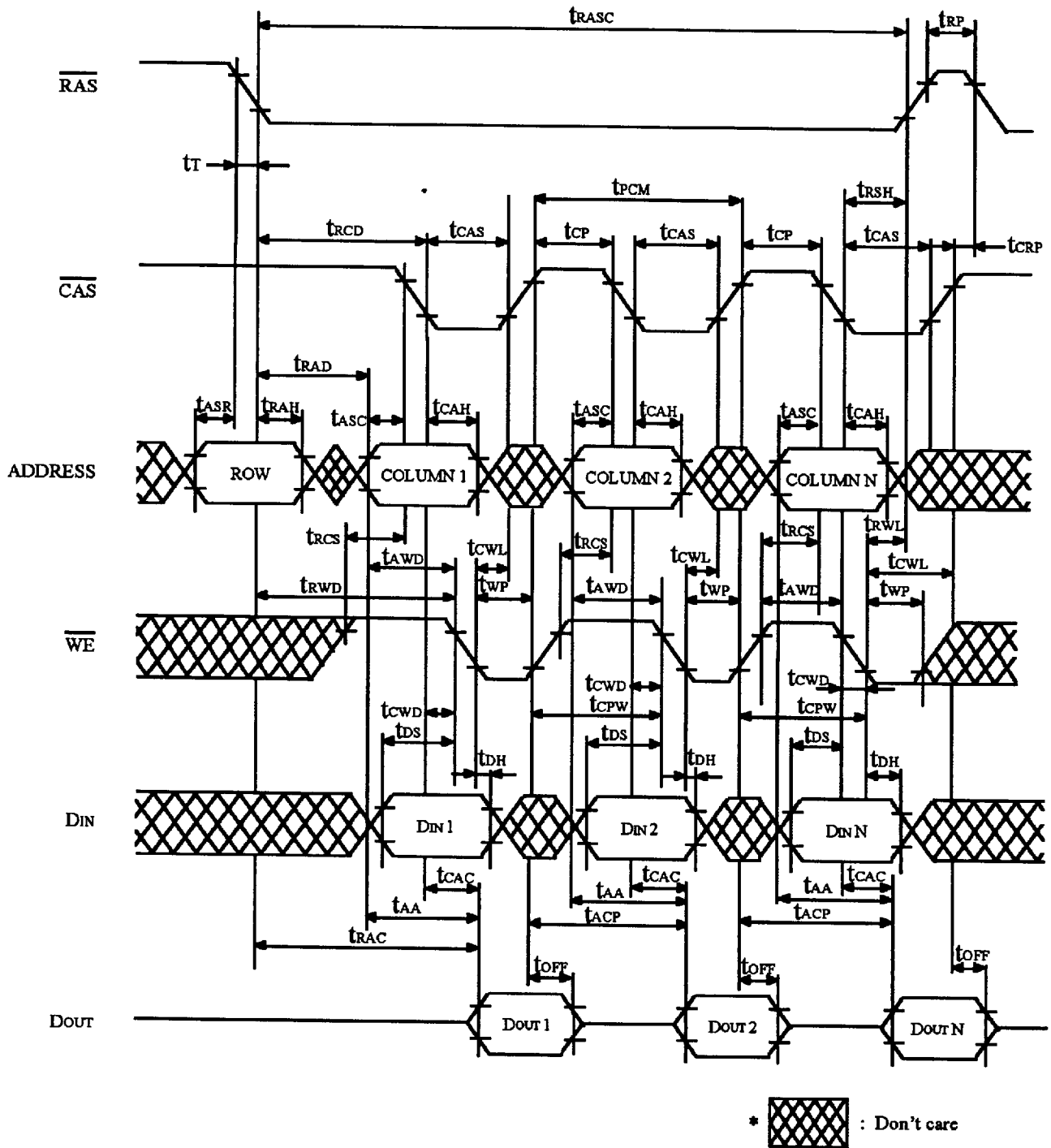


FIGURE 11. FAST PAGE MODE READ MODIFY WRITE CYCLE

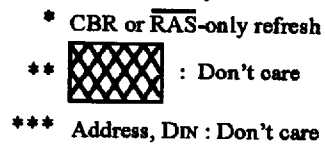


FIGURE 12. TEST MODE CYCLE

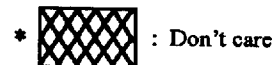


FIGURE 13. TEST MODE SET CYCLE



Test Mode Reset Cycle

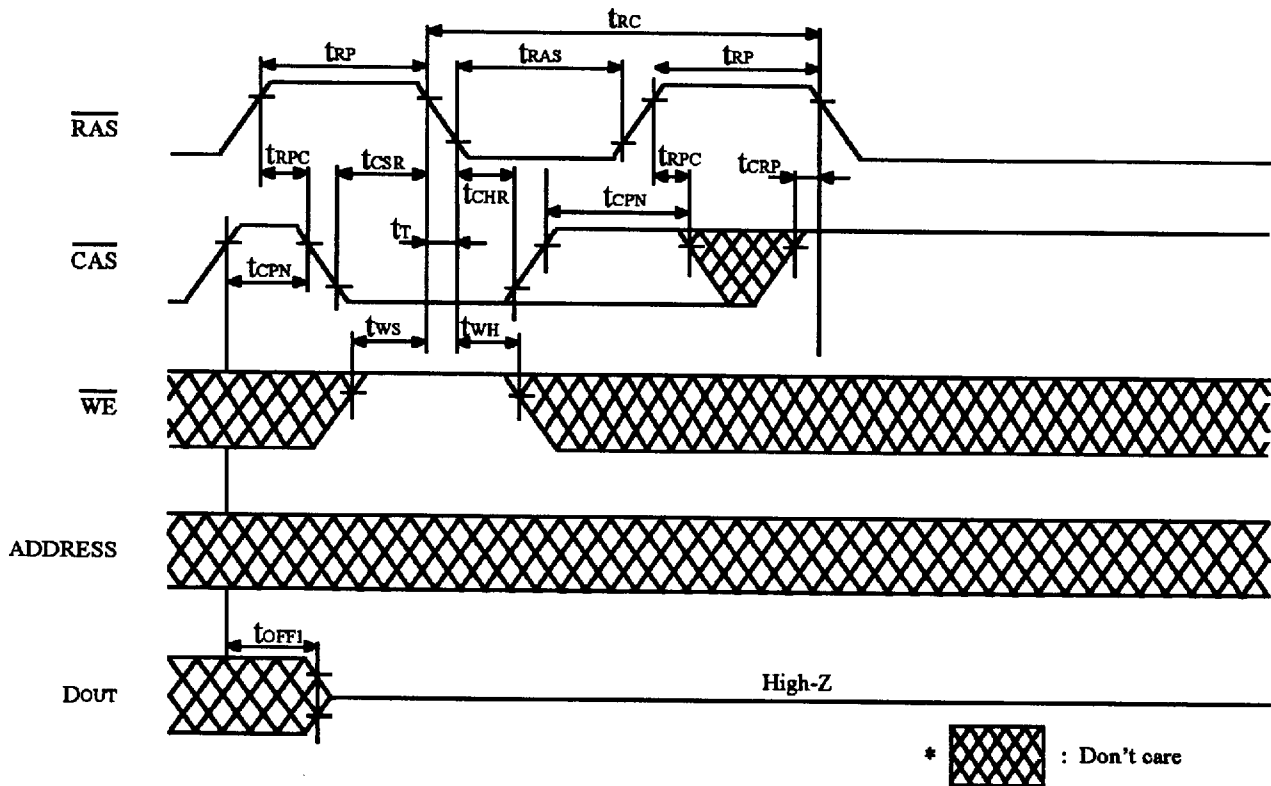


FIGURE 14. $\overline{\text{CAS}}$ BEFORE $\overline{\text{RAS}}$ REFRESH CYCLE

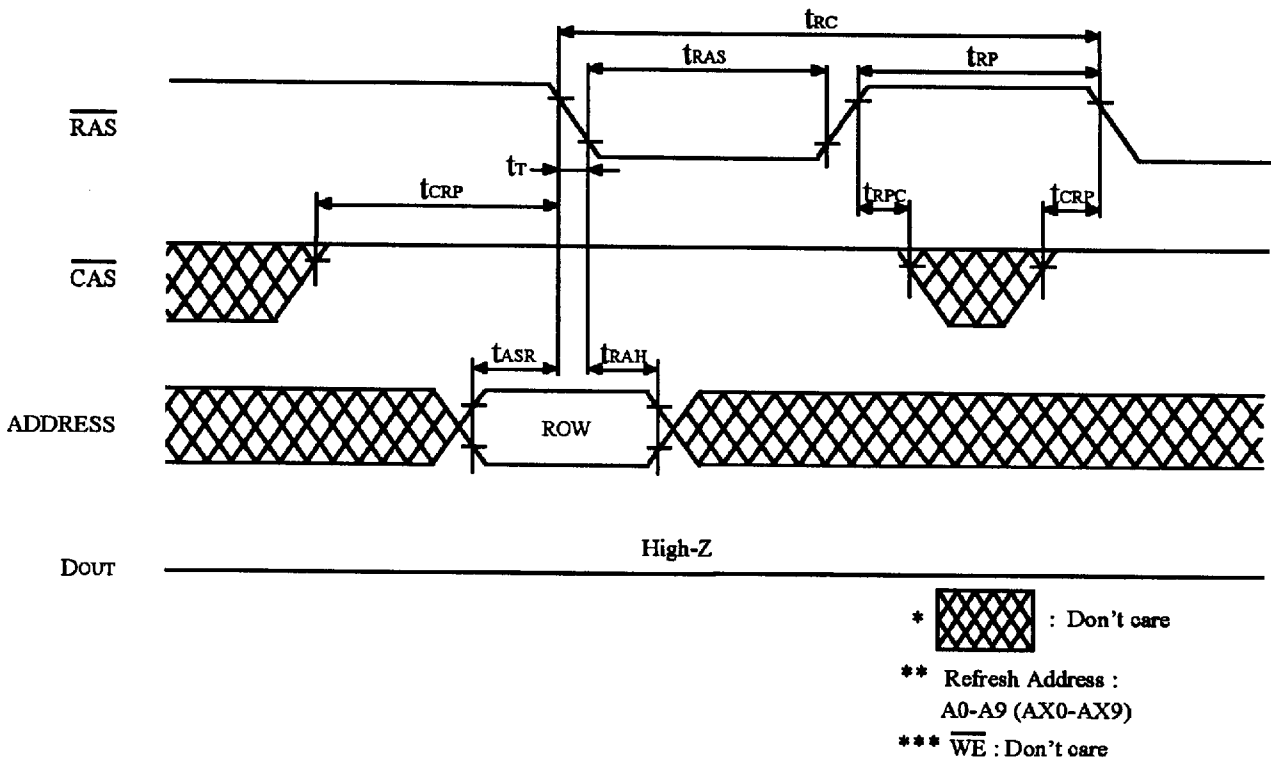


FIGURE 15. $\overline{\text{RAS}}$ ONLY REFRESH CYCLE

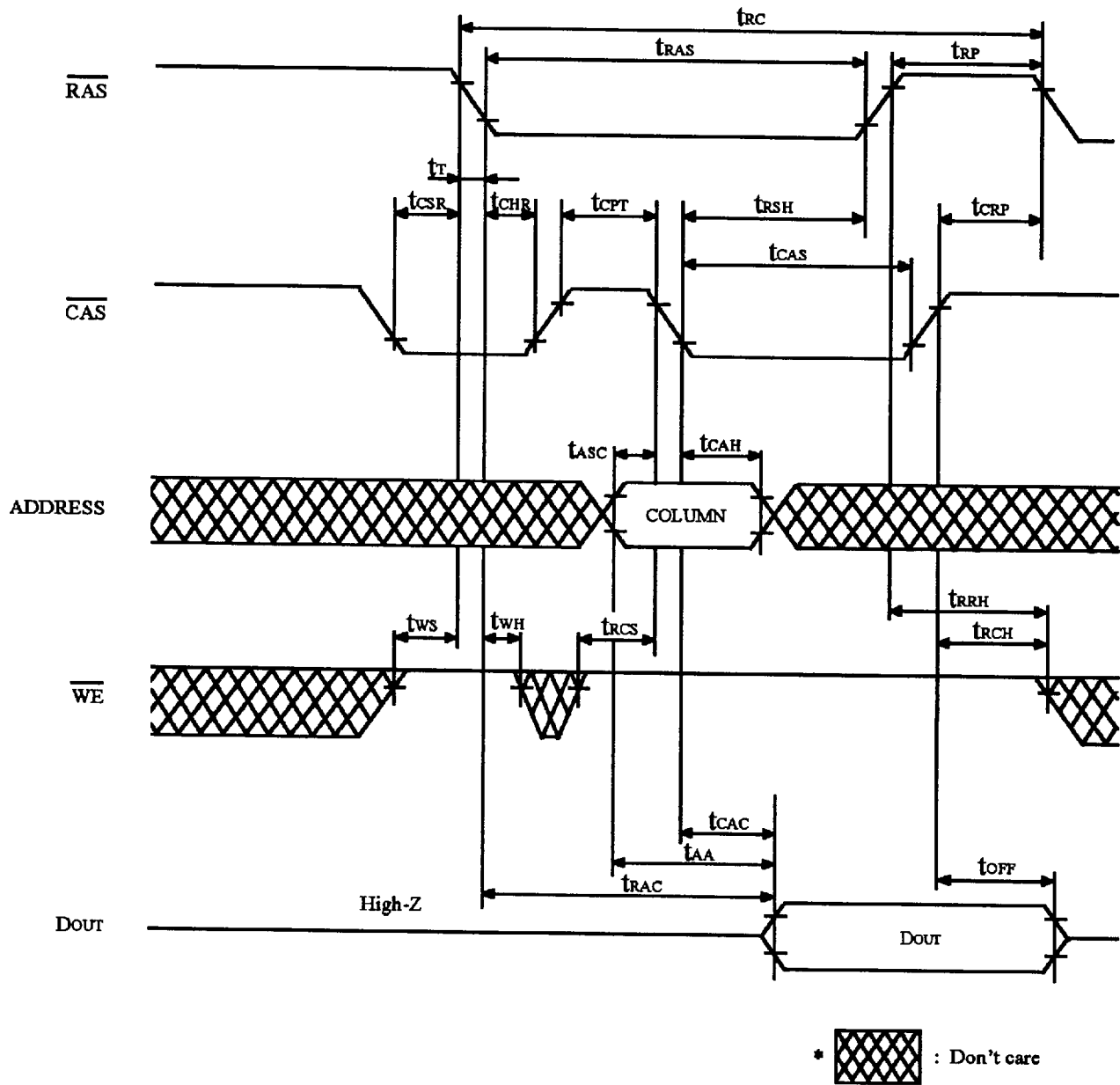


FIGURE 16. $\overline{\text{CAS}}$ BEFORE $\overline{\text{RAS}}$ REFRESH COUNTER CHECK CYCLE (READ)

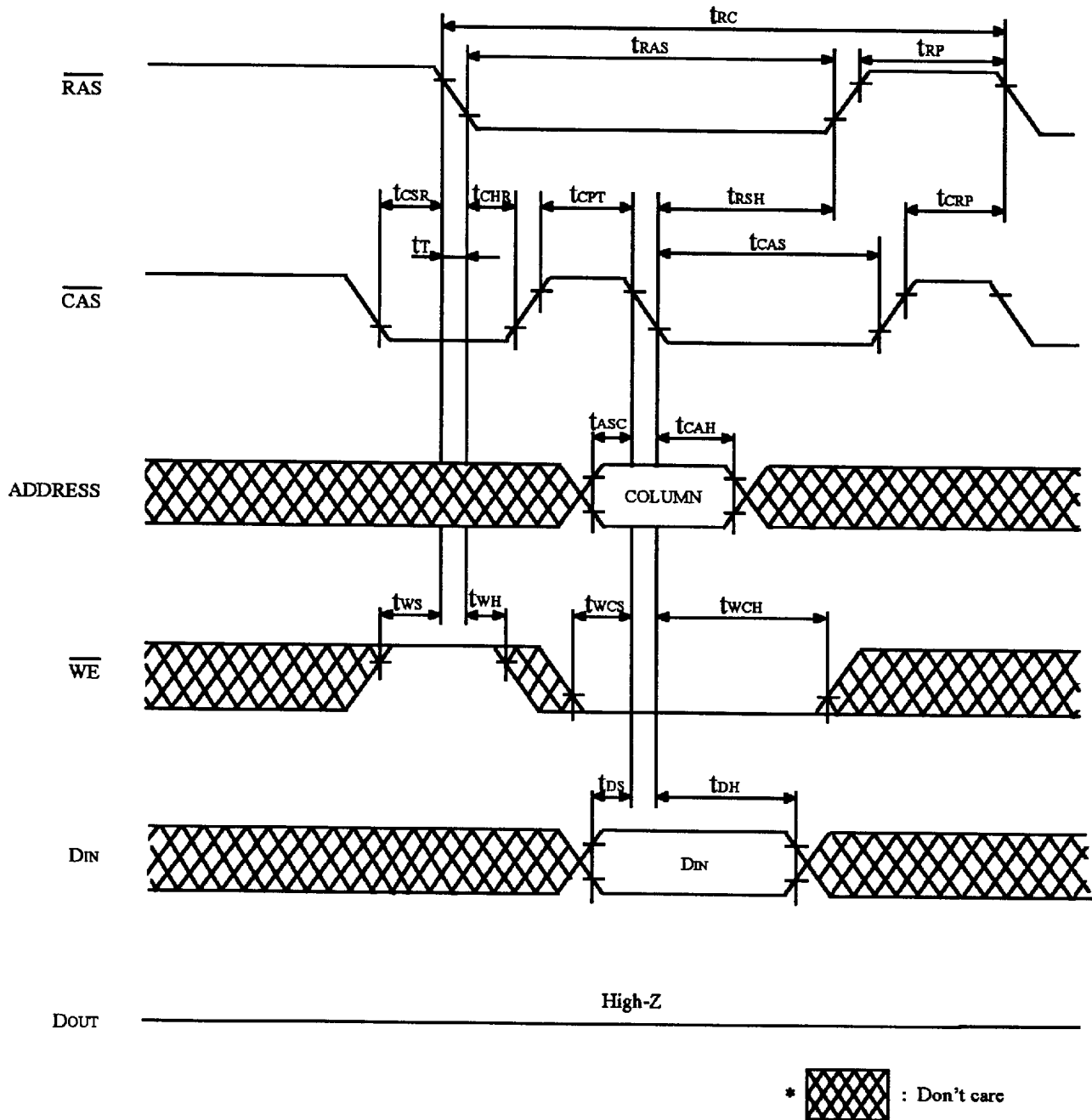
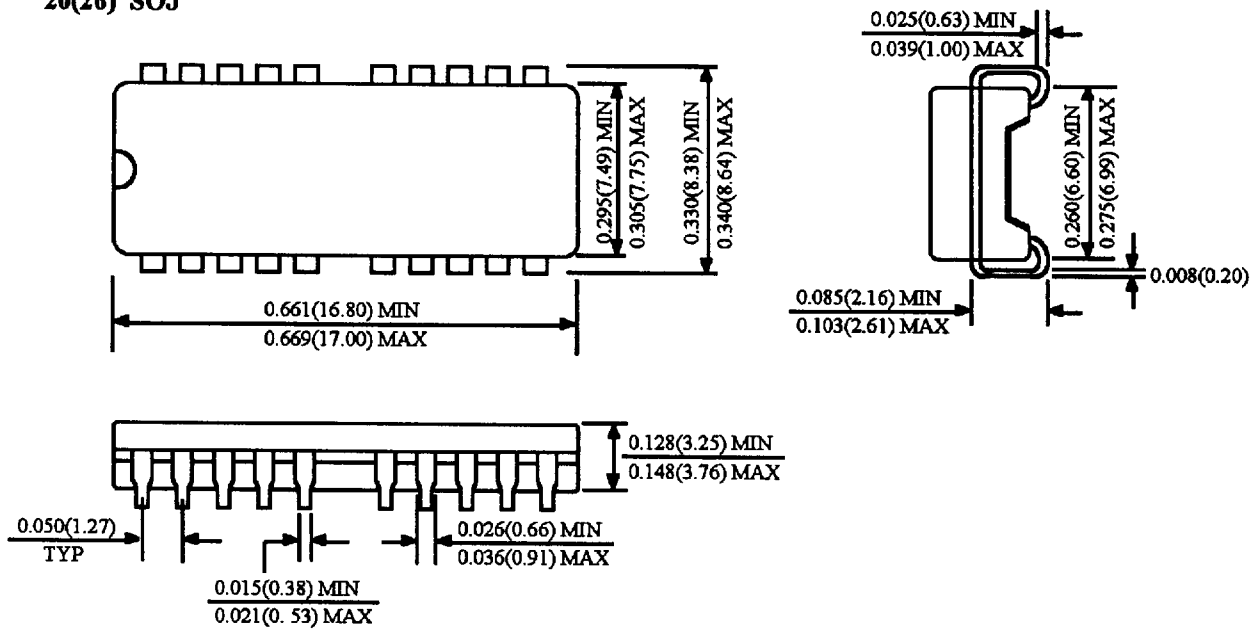


FIGURE 17. $\overline{\text{CAS}}$ BEFORE $\overline{\text{RAS}}$ REFRESH COUNTER CHECK CYCLE (WRITE)

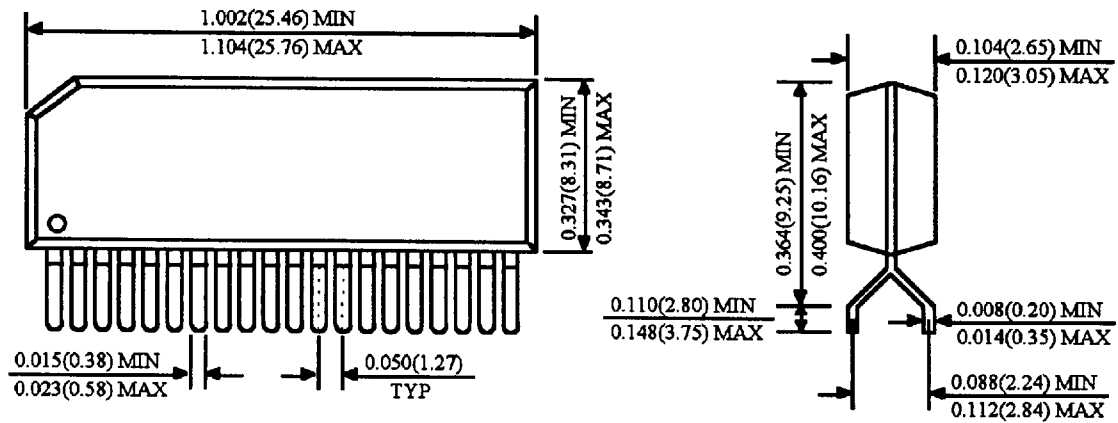
Package Dimension

Unit: Inches (mm)

20(26) SOJ



20 ZIP

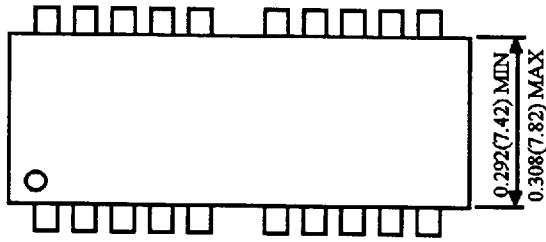




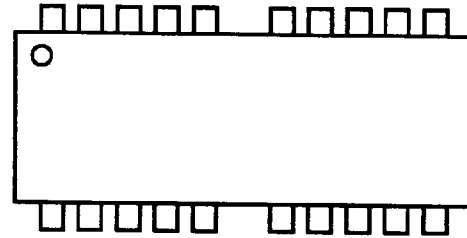
Package Dimension

Unit: Inches (mm)

20 (26) TSOP (TYPE. II)



GM71C4100CT/CLT



GM71C4100CR/CLR

